



# Lasers

## ECE 5131

**Credit Hours:**

3.00

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**Course Levels:**

Undergraduate (1000-5000 level)

Graduate (5000-8000 level)

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**Course Components:**

Lecture

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**Course Description:**

Atomic interaction with radiation, cavities with gain, optical processes in semiconductors, strain in laser design, diode lasers, and advanced semiconductor lasers.

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**Prerequisites and Co-requisites:**

Prereq: 3010 and 3030, or Grad standing in Engineering, Biological Sciences, or Math and Physical Sciences.

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**Course Goals / Objectives:**

- Master physics of emission, absorption, and optical gain
  - Master physics of optical resonators, with and without gain
  - Master dynamics of lasing
  - Be competent in understanding gain and lasing in semiconductor lasers
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**Course Topics:**

- Review of electromagnetics
  - Coherence
  - Optical processes in semiconductors
  - Strain in laser design
  - Dispersion and attenuation
  - Resonant cavities
  - Einstein coefficients, lineshape
  - Optical amplification and lineshape broadening
  - Lasing dynamics, gain saturation
  - Review of density of states, quasi-Fermi levels
  - Semiconductor materials for diode lasers
  - Double-heterojunction semiconductor lasers
  - Gain-guided and index guided semiconductor lasers
  - Quantum well lasers
  - Strained quantum well lasers
  - Strained quantum dot lasers
  - Advanced semiconductor lasers
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**Designation:**

Elective